

QT-Brightek Lamp Series

5mm IR Lamp LED

Part No.: QBED8340

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	Version# 1.0	

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Introduction

Feature:

- Water clear lens
- Package in bulk
- High radiant intensity
- Peak wavelength $\lambda_p=850\text{nm}$
- 40 degree viewing angle

Description:

This device is spectrally match with phototransistor, photodiode, and infrared receiver module

Application:

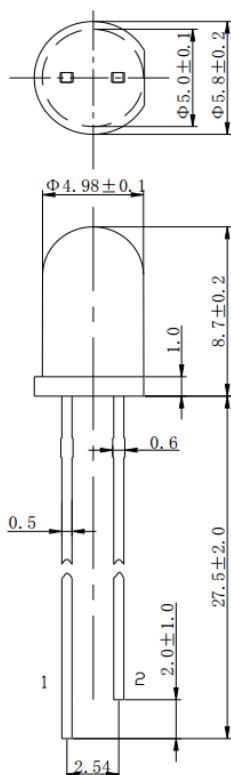
- Free air transmission system
- Optoelectronic switch
- Infrared applied system
- Smoke Detector

Certification & Compliance:

- TS16949
- ISO9001
- RoHS Compliant



Dimension:



- 1、Anode
2、Cathode

Units: mm / tolerance = +/-0.2mm

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Electrical / Optical Characteristic (Ta=25 °C)

Parameter	Symbol	Test Condition	Output			Units
			Min.	Typ.	Max.	
Forward Voltage	V_F	$I_F=50\text{mA}$	-	1.4	1.60	V
Pulse Forward Voltage	V_{FP}	$I_{FP}=700\text{mA}$, $t_o=10\mu\text{s}$	-	-	3.50	
Reverse Current	I_R	$V_R=5\text{V}$	-	-	10	μA
Radiant Intensity	I_E	$I_F=50\text{mA}$	30	45	-	mW/sr
		$I_F=100\text{mA}$, $t=20\text{ms}$	60	80	-	
Peak Radiation Wavelength	λ_P	$I_F=50\text{mA}$	-	850	-	nm
Half Spectrum Width	$\Delta\lambda$	$I_F=50\text{mA}$	-	40	-	nm
Viewing Angle	$2\theta_{1/2}$	$I_F=50\text{mA}$	-	40	-	deg
Switch Time	t_r/t_f	$I_{FP}=100\text{mA}$, $f=1\text{KHz}$, $t_p/T=1\%$	-	25/15	-	ns

Absolute Maximum Rating

Parameter	Symbol	Rating	Units
Continuous Forward Current	I_F	100	mA
Peak Forward Current	I_{FP}	1	A
Reverse Voltage	V_R	5	V
Power Dissipation at (or below) 25 °C Free Air Temperature	P_d	120	mW
Operating Temperature	T_{opr}	-25 ~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +100	°C

Characteristic Curves

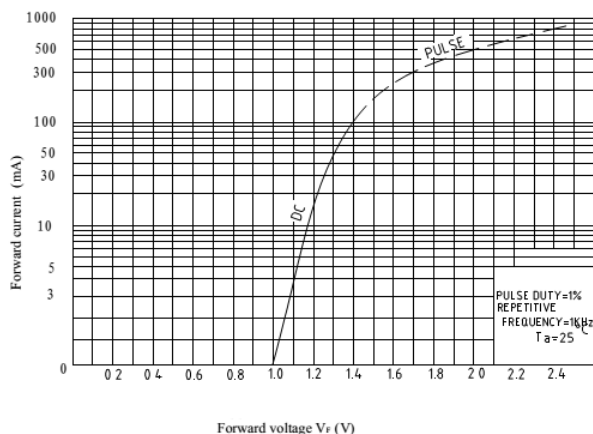


Fig.1 Forward Current vs. Forward Voltage

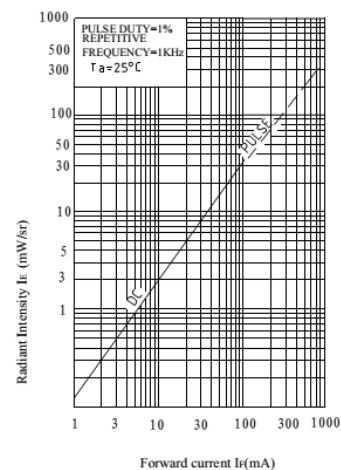


Fig.2 Radiant Intensity vs. Forward Current

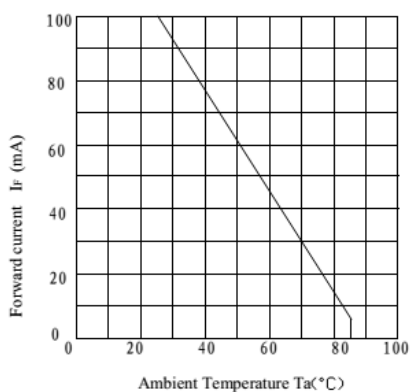


Fig.3 Forward Current vs. Ambient Temperature

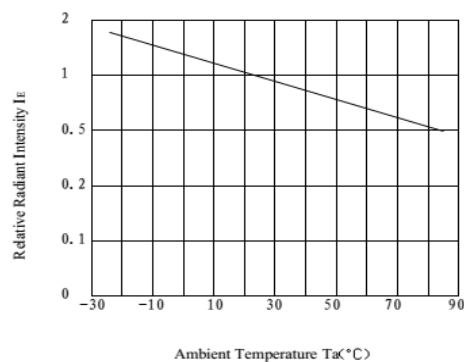


Fig.4 Relative Radiant Intensity vs. Ambient Temperature

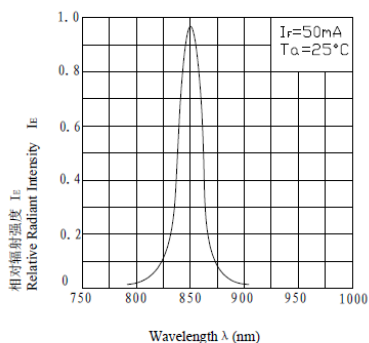


Fig.5 Relative Radiant Intensity vs. Wavelength

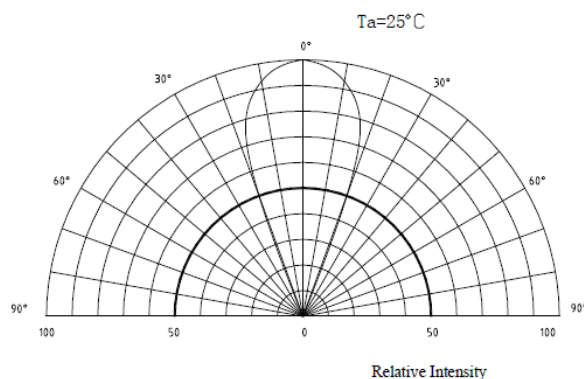


Fig.6 Relative Radiant Intensity vs. Angular Displacement

Packing

500pcs per bag

Labeling



Part No: _____

Customer P/N: _____

Item: _____

Q'ty: _____

Vf: _____

Iv: _____

WI: _____

Date: _____

Made in China

Ordering Information

Part #	Orderable Part #	Spec Range	Quantity per bag
QBED8340	QBED8340	I _e =80mW mW/sr. @ I _F =100mA, t=20ms / λ _P =850nm typ.	500pcs

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Revision History

Description:	Revision #	Revision Date
New Release of QBED8340	V1.0	03/27/2014

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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